Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
LI	0	1999-67858	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 14:46
L2	0	1999-00067858	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 14:46
L3	0	1999-0067858	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 14:46
L4	41	"67858"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 14:47
L5	52	kim-se-jun.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 14:47
L6	3	("6191835"   "6407782"   "6429916").PN. OR ("6912024").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/18 14:56
L7	40145	("349").CLAS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/08/18 14:56
L8	6839	((438/30) or (430/20) or (216/23) or (216/39) or (216/40) or (216/41) or (216/49) or (216/55) or (216/100) or (216/108)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/08/18 14:58
L9	46440	7 8	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:01
L10	64602	transparent nearl electrode (transparen\$4 nearl electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:59
LII	51011	transparent near1 conduct\$4 (transparen\$4 near1 metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:59

L12	437413	ito (indium near1 oxide) (tin near1 oxide) izo (zinc near1 oxide) sno2 "sno.sub.2"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:58
L13	101961	10 11	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:03
L14	37914	12 same 13	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:04
L15	7486692	heat\$4 anneal\$4 ("100" near1 c) ("100" near1 celsius) ("200" near1 c) ("200" near1 celsius) ("150" near1 c) ("150" near1 celsius) ("175" near1 c) ("175" near1 celsius) temperature celsius fahrenheit degree ".deg."	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:01
L16	699097	crystalliz\$6 crystallize crystallization amorphous crystalline	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:00
L17	332510	15 same 16	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:07
L18	725	14 same 17	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:08
L19	548	18 same (catalyst catalysis catalysts ni cu in sn mo tn w cr hf nickel copper indium tin molybdenum tungsten chromium hafnium)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:58
L20	147	19 same (etch\$ selectivity selectively selective\$4 remov\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:57
L21	1	19 same (etch\$ selectivity selectively selective\$4 remov\$4 pattern\$4).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:00
L22	778376	(catalyst catalysis catalysts ni cu in sn mo tn w cr hf nickel copper indium tin molybdenum tungsten chromium hafnium).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:58

L23	24668	(ito (indium near1 oxide) (tin near1 oxide) izo (zinc near1 oxide) sno2 "sno.sub.2").clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:58
L25	7178	transparent near1 electrode.clm. (transparen\$4 near1 electrode).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 15:59
L26	6412	transparent near1 conduct\$4.clm. (transparen\$4 near1 metal).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:00
L27	33930	23 25 26	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:00
L28	19061	22 and 27	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:00
L29	79335	(crystalliz\$6 crystallize crystallization amorphous crystalline).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:03
L30	2530	28 and 29	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:00
L31	1231900	(etch\$ selectivity selectively selective\$4 remov\$4 pattern\$4).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ÓN	2006/08/18 16:01
L32	1384024	(etch\$ selectivity selectively selective\$4 remov\$4 pattern\$4 dissol\$6 strip\$4).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:01
L33	1123	· 30 and 32	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:01
L34	942418	(heat\$4 anneal\$4 ("100" near1 c) ("100" near1 celsius) ("200" near1 c) ("200" near1 celsius) ("150" near1 c) ("150" near1 celsius) ("175" near1 c) ("175" near1 celsius) temperature celsius fahrenheit degree ".deg."). clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:02

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L35	463	33 and 34	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:02
L36	236	35 and (maskless selectiv\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:02
L37	143	35 and (lcd liquid near1 crystall\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:03
L38	189	35 and (lcd liquid near1 crystal\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:03
L39	106	35 and (lcd liquid near1 crystal\$6).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:03
L40	105	39 not 20	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:03
L41	4985	(etch\$4 remov\$4 pattern\$4 strip\$4 dissol\$6) near4 (crystalliz\$6 crystallize crystallization amorphous crystalline).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:04
L42	47	40 and 41	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:16
L43	174	four-mask	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:17
L44	81	43 and 9	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/18 16:17
SI	187	(216/23).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/08/18 14:46

S2	6	S1 and catalyst	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/17 13:57
S3	53	S1 and amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/17 13:57
S4	24	S1 and amorphous with (etch\$4 remov\$4 dissol\$7 oxalic acid ph)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/08/17 13:58